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Operational Amplifiers



Low Noise Operational Amplifiers

BA4558xxx, BA4558Rxxx

● General Description

Normal BA4558 and high-reliability BA4558R integrate two independent Op-Amps on a single chip. Especially, this series is suitable for any audio applications due to low noise and low distortion characteristics and are usable for other many applications by wide operating supply voltage range. BA4558R is high-reliability products with extended operating temperature range and high ESD tolerance.

● Features

- High voltage gain, low noise, low distortion
- Wide operating supply voltage
- Internal ESD protection
- Wide operating temperature Range

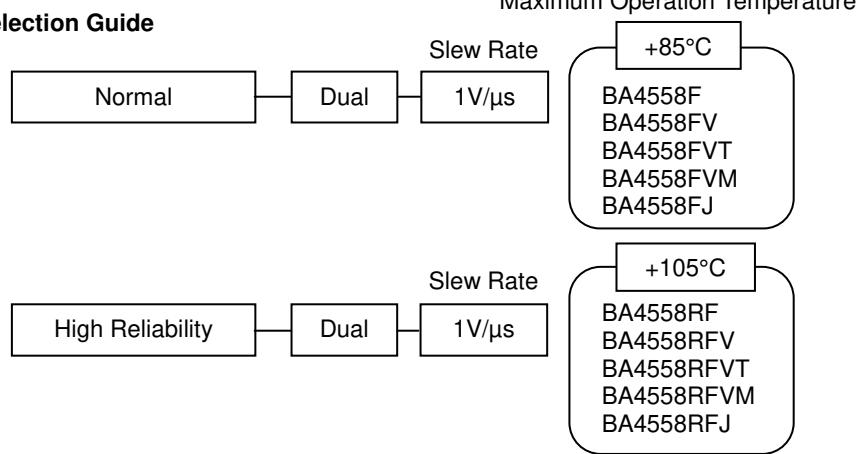
● Packages

	W(Typ.) x D(Typ.) x H(Max.)
MSOP8	2.90mm x 4.00mm x 0.90mm
SSOP-B8	3.00mm x 6.40mm x 1.35mm
SOP8	5.00mm x 6.20mm x 1.71mm
TSSOP-B8	3.00mm x 6.40mm x 1.20mm
SOP-J8	4.90mm x 6.00mm x 1.65mm

● Key Specification

- Wide Operating Supply Voltage
(split supply): $\pm 4.0\text{V}$ to $\pm 15\text{V}$
- Wide Temperature Range: BA4558: -40°C to +85°C
BA4558R: -40°C to +105°C
- High Slew Rate: $1\text{V}/\mu\text{s}(\text{Typ.})$
- Total Harmonic Distortion : $0.005\%(\text{Typ.})$
- Input Referred Noise Voltage : $12\text{nV}/\sqrt{\text{Hz}}$ (Typ.)

● Selection Guide



● Block Diagram

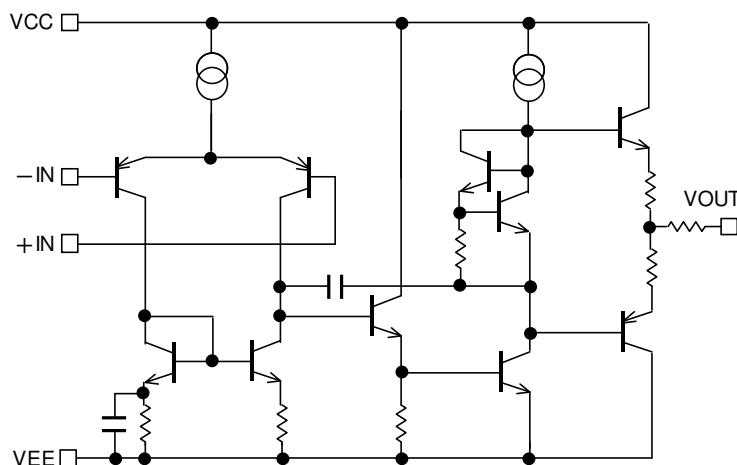
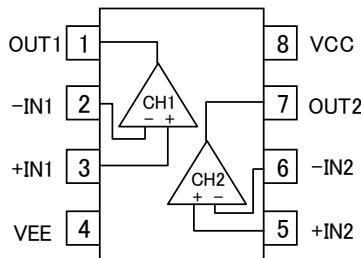


Fig. 1 Simplified schematic

○ Product structure : Silicon monolithic integrated circuit ○ This product is not designed protection against radioactive rays.

● Pin Configuration(TOP VIEW)



SOP8	SSOP-B8	TSSOP-B8	MSOP8	SOP-J8
BA4558F BA4558RF	BA4558FV BA4558RFV	BA4558FVT BA4558RFVT	BA4558FVM BA4558RFVM	BA4558FJ BA4558RFJ

Package				
SOP8	SSOP-B8	TSSOP-B8	MSOP8	SOP-J8
BA4558F BA4558RF	BA4558FV BA4558RFV	BA4558FVT BA4558RFVT	BA4558FVM BA4558RFVM	BA4558FJ BA4558RFJ

● Ordering Information

B A 4 5 5 8 x x x x	-	x x
Part Number BA4558xxx BA4558Rxxx	Package F: SOP8 FV: SSOP-B8 FJ: SOP-J8 FVT: TSSOP-B8 FVM: MSOP8	Packaging and forming specification E2: Embossed tape and reel (SOP8/SSOP-B8/TSSOP-B8/SOP-J8) TR: Embossed tape and reel (MSOP8)

● Line-up

Topr	Operating Supply Voltage (split supply)	Supply Current (Typ.)	Slew Rate (Typ.)	Package		Orderable Part Number
-40°C to +85°C	$\pm 4.0V$ to $\pm 15.0V$	3mA	1V/ μ s	SOP8	Reel of 2500	BA4558F-E2
				SSOP-B8	Reel of 2500	BA4558FV-E2
				TSSOP-B8	Reel of 3000	BA4558FVT-E2
				MSOP8	Reel of 3000	BA4558FVM-TR
				SOP-J8J	Reel of 2500	BA4558FJ-E2
				SOP8	Reel of 2500	BA4558RF-E2
				SSOP-B8	Reel of 2500	BA4558RFV-E2
				TSSOP-B8	Reel of 3000	BA4558RFVT-E2
				MSOP8	Reel of 3000	BA4558RFVM-TR
				SOP-J8	Reel of 2500	BA4558RFJ-E2

● Absolute Maximum Ratings (Ta=25°C)

OBA4558, BA4558R

Parameter	Symbol	Ratings		Unit
		BA4558	BA4558R	
Supply Voltage	VCC-VEE	+36		V
Power dissipation	Pd	SOP8	552 ^{*1*5}	690 ^{*1*5}
		SSOP-B8	500 ^{*2*5}	625 ^{*2*5}
		TSSOP-B8	500 ^{*2*5}	625 ^{*2*5}
		MSOP8	470 ^{*3*5}	587 ^{*3*5}
		SOP-J8	540 ^{*4*5}	675 ^{*4*5}
Differential Input Voltage ^{*5}	Vid	VCC-VEE	+36	V
Input common-mode voltage range	Vicm	VEE to VCC	(VEE-0.3) to VEE+36	V
Operating Supply Voltage	Vopr	+8 to +30 (± 4 to ± 15)		V
Operating Temperature	Topr	-40 to +85	-40 to +105	°C
Storage Temperature	Tstg	-55 to +125	-55 to +150	°C
Maximum Junction Temperature	Tjmax	+125	+150	°C

Note: Absolute maximum rating item indicates the condition which must not be exceeded.

Application of voltage in excess of absolute maximum rating or use out absolute maximum rated temperature environment may cause deterioration of characteristics.

*1 To use at temperature above Ta=25°C reduce 5.52mW.

*2 To use at temperature above Ta=25°C reduce 5mW.

*3 To use at temperature above Ta=25°C reduce 4.7mW.

*4 To use at temperature above Ta=25°C reduce 5.4mW.

*5 Mounted on a FR4 glass epoxy PCB(70mm×70mm×1.6mm).

*6 The voltage difference between inverting input and non-inverting input is the differential input voltage.

Then input terminal voltage is set to more than VEE.

● Electrical Characteristics

OBA4558 (Unless otherwise specified VCC=+15V, VEE=-15V)

Parameter	Symbol	Temperature Range	Limits			Unit	Condition
			Min.	Typ.	Max.		
Input Offset Voltage ^{*7}	V _{IO}	25°C	-	0.5	6	mV	V _{OUT} =0V
Input Offset Current ^{*7}	I _{IO}	25°C	-	5	200	nA	V _{OUT} =0V
Input Bias Current ^{*8}	I _B	25°C	-	60	500	nA	V _{OUT} =0V
Supply Current	I _{CC}	25°C	-	3	6	mA	R _L =∞, All Op-Amps, V _{IN+} =0V
Maximum Output Voltage	V _{OM}	25°C	±10	±13	-	V	R _L ≥2kΩ
		25°C	±12	±14	-		R _L ≥10kΩ
Large Signal Voltage Gain	A _V	25°C	86	100	-	dB	R _L ≥2kΩ, V _{OUT} =±10V, V _{ICM} =0V
Input Common-mode Voltage Range	V _{ICM}	25°C	±12	±14	-	V	-
Common-mode Rejection Ratio	C _{MRR}	25°C	70	90	-	dB	R _i ≤10kΩ
Power Supply Rejection Ratio	P _{SRR}	25°C	76.3	90	-	dB	R _i ≤10kΩ
Slew Rate	S _R	25°C	-	1	-	V/μs	A _V =0dB, R _L ≥2kΩ
Unity Gain Frequency	f _T	25°C	-	2	-	MHz	R _L =2kΩ
Total Harmonic Distortion	T _H D+N	25°C	-	0.005	-	%	A _V =20dB, R _L =10kΩ V _{IN} =0.05Vrms, f=1kHz
Input Referred Noise Voltage	V _n	25°C	-	12	-	nV/√Hz	R _S =100Ω, V _i =0V, f=1kHz
			-	1.8	-	μVrms	R _S =100Ω, V _i =0V, DIN-AUDIO
Channel Separation	C _S	25°C	-	105	-	dB	f=1kHz

^{*7} Absolute value

^{*8} Current direction: Since first input stage is composed with PNP transistor, input bias current flows out of IC.

OBA4558R (Unless otherwise specified VCC=+15V, VEE=-15V, Full range -40°C to +105°C)

Parameter	Symbol	Temperature Range	Limits			Unit	Condition
			Min.	Typ.	Max.		
Input Offset Voltage ^{*9}	V _{io}	25°C	-	0.5	6	mV	V _{OUT} =0V
		Full range	-	-	7		
Input Offset Current ^{*9}	I _{io}	25°C	-	5	200	nA	V _{OUT} =0V
		Full range	-	-	200		
Input Bias Current ^{*10}	I _b	25°C	-	60	500	nA	V _{OUT} =0V
		Full range	-	-	800		
Supply Current	I _{CC}	25°C	-	3	6	mA	RL=∞, All Op-Amps, V _{IN+} =0V
		Full range	-	-	6.5		
Maximum Output Voltage	V _{OM}	25°C	±10	±13	-	V	RL≥2kΩ
		Full range	±10	-	-		RL≥10kΩ
		25°C	±12	±14	-		
Large Signal Voltage Gain	AV	25°C	86	100	-	dB	RL≥2kΩ, V _{OUT} =±10V, V _{ICM} =0V
		Full range	83	-	-		
Input Common-mode Voltage Range	V _{ICM}	25°C	±12	±14	-	V	-
		Full range	±12	-	-		
Common-mode Rejection Ratio	CMRR	25°C	70	90	-	dB	R _i ≤10kΩ
Power Supply Rejection Ratio	PSRR	25°C	76.5	90	-	dB	R _i ≤10kΩ
Slew Rate	SR	25°C	-	1	-	V/μs	AV=0dB, RL=2kΩ CL=100pF
Unity Gain Frequency	f _t	25°C	-	2	-	MHz	RL=2kΩ
Total Harmonic Distortion	THD+N	25°C	-	0.005	-	%	AV=20dB, RL=10kΩ VIN=0.05Vrms, f=1kHz
Input Referred Noise Voltage	V _n	25°C	-	12	-	nV/√Hz	RS=100Ω, V _i =0V, f=1kHz
			-	1.8	-	μVrms	RS=100Ω, V _i =0V, DIN-AUDIO
Channel Separation	CS	25°C	-	105	-	dB	R ₁ =100Ω, f=1kHz

^{*9} Absolute value^{*10} Current direction: Since first input stage is composed with PNP transistor, input bias current flows out of IC.

Description of electrical characteristics

Described here are the terms of electric characteristics used in this datasheet. Items and symbols used are also shown. Note that item name and symbol and their meaning may differ from those on another manufacturer's document or general document.

1. Absolute maximum ratings

Absolute maximum rating item indicates the condition which must not be exceeded. Application of voltage in excess of absolute maximum rating or use out of absolute maximum rated temperature environment may cause deterioration of characteristics.

1.1 Power supply voltage (VCC-VEE)

Indicates the maximum voltage that can be applied between the positive power supply terminal and negative power supply terminal without deterioration or destruction of characteristics of internal circuit.

1.2 Differential input voltage (Vid)

Indicates the maximum voltage that can be applied between non-inverting terminal and inverting terminal without deterioration and destruction of characteristics of IC.

1.3 Input common-mode voltage range (Vicm)

Indicates the maximum voltage that can be applied to non-inverting terminal and inverting terminal without deterioration or destruction of characteristics. Input common-mode voltage range of the maximum ratings not assure normal operation of IC. When normal operation of IC is desired, the input common-mode voltage of characteristics item must be followed.

1.4 Power dissipation (Pd)

Indicates the power that can be consumed by specified mounted board at the ambient temperature 25°C(normal temperature). As for package product, Pd is determined by the temperature that can be permitted by IC chip in the package (maximum junction temperature)and thermal resistance of the package.

2. Electrical characteristics item**2.1 Input offset voltage (Vio)**

Indicates the voltage difference between non-inverting terminal and inverting terminal. It can be translated into the input voltage difference required for setting the output voltage at 0V.

2.2 Input offset current (Iio)

Indicates the difference of input bias current between non-inverting terminal and inverting terminal.

2.3 Input bias current (Ib)

Indicates the current that flows into or out of the input terminal. It is defined by the average of input bias current at non-inverting terminal and input bias current at inverting terminal.

2.4 Input common-mode voltage range (Vicm)

Indicates the input voltage range where IC operates normally.

2.5 Large signal voltage gain (AV)

Indicates the amplifying rate (gain) of output voltage against the voltage difference between non-inverting terminal and Inverting terminal. It is normally the amplifying rate (gain) with reference to DC voltage.

$$Av = (\text{Output voltage fluctuation}) / (\text{Input offset fluctuation})$$

2.6 Circuit current (ICC)

Indicates the IC current that flows under specified conditions and no-load steady status.

2.7 Output saturation voltage (VOM)

Signifies the voltage range that can be output under specific output conditions.

2.8 Common-mode rejection ratio (CMRR)

Indicates the ratio of fluctuation of input offset voltage when in-phase input voltage is changed. It is normally the fluctuation of DC.

$$CMRR = (\text{Change of Input common-mode voltage}) / (\text{Input offset fluctuation})$$

2.9 Power supply rejection ratio (PSRR)

Indicates the ratio of fluctuation of input offset voltage when supply voltage is changed. It is normally the fluctuation of DC.

$$PSRR = (\text{Change of power supply voltage}) / (\text{Input offset fluctuation})$$

2.10 Channel Separation (CS)

Indicates the fluctuation of input offset voltage or that of output voltage with reference to the change of output voltage of driven channel.

2.11 Slew Rate (SR)

SR is a parameter that shows movement speed of operational amplifier. It indicates rate of variable output voltage as unit time.

2.12 Transition Frequency (ft)

Indicates a frequency where the voltage gain of operational amplifier is 1.

2.13 Total Harmonic Distortion (THD+N)

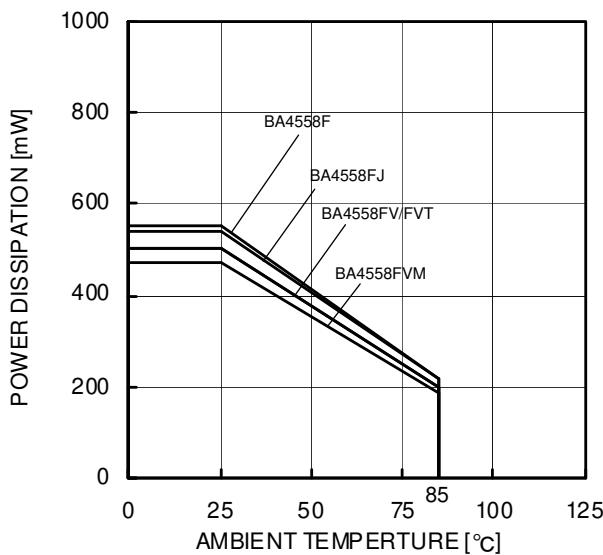
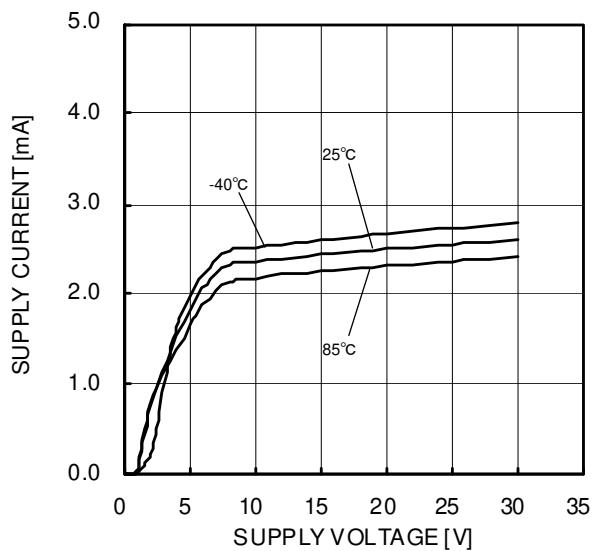
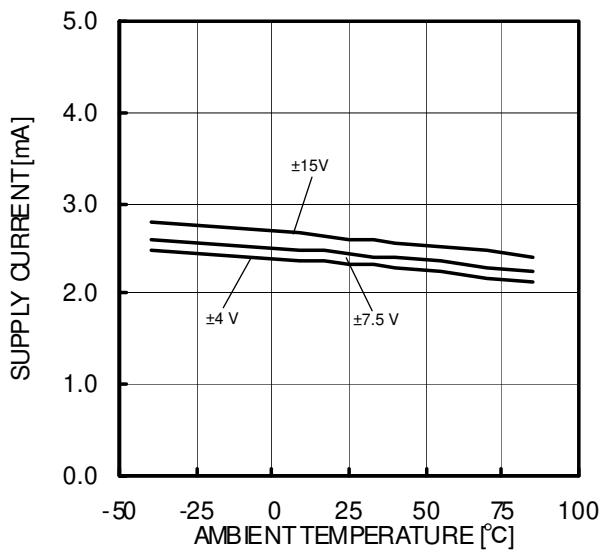
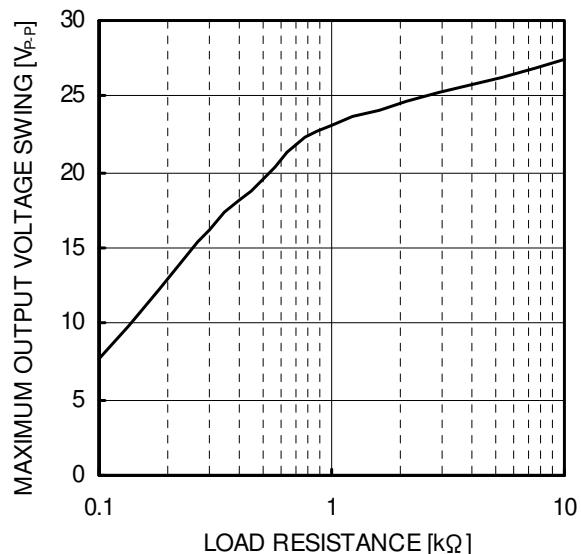
Indicates the fluctuation of input offset voltage or that of output voltage with reference to the change of output voltage of driven channel.

2.14 Input Referred Noise Voltage (Vn)

Indicates a noise voltage generated inside the operational amplifier equivalent by ideal voltage source connected in series with input terminal.

● Typical Performance Curves

○ BA4558

Fig.2
Derating CurveFig.3
Supply Current – Supply VoltageFig.4
Supply Current – Ambient TemperatureFig.5
Maximum Output Voltage Swing
- Load Resistance
(VCC/VEE = +15V/-15V, Ta = 25°C)

(*) The above data is measurement value of typical sample, it is not guaranteed.

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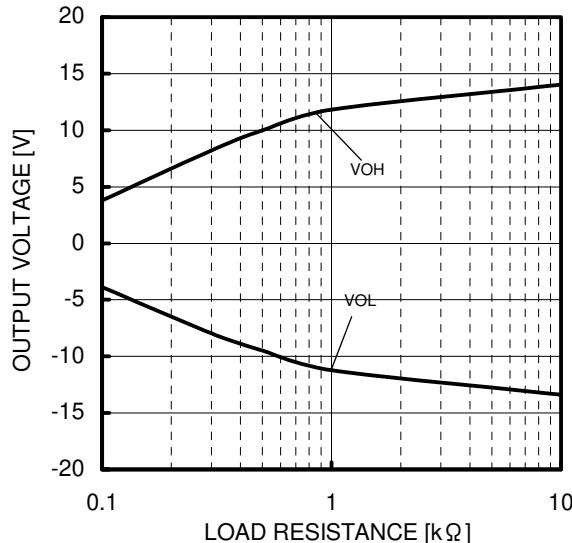


Fig.6
Maximum Output Voltage
- Load Resistance
(VCC/VEE=+15V/-15V, Ta=25°C)

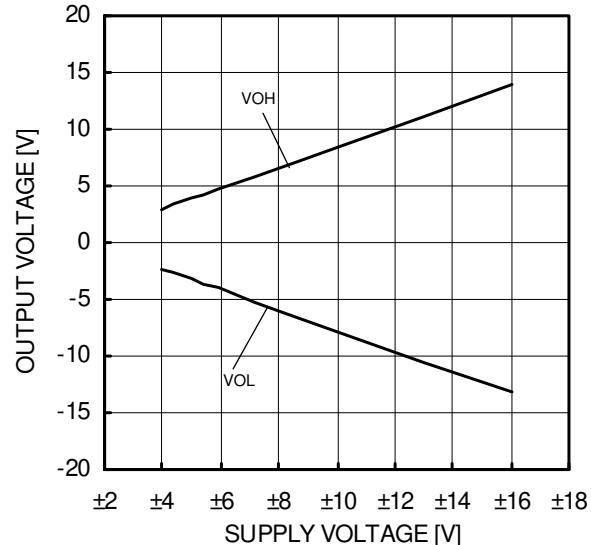


Fig.7
Maximum Output Voltage
- Supply Voltage
(RL=2kΩ, Ta=25°C)

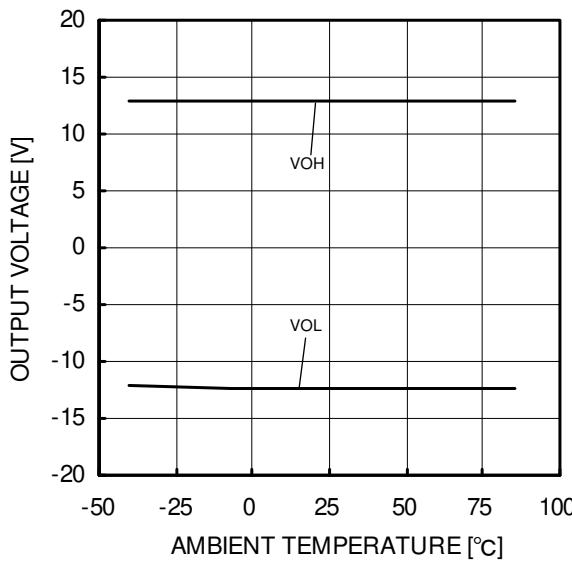


Fig.8
Maximum Output Voltage
- Ambient Temperature
(VCC/VEE=+15V/-15V, RL=2kΩ)

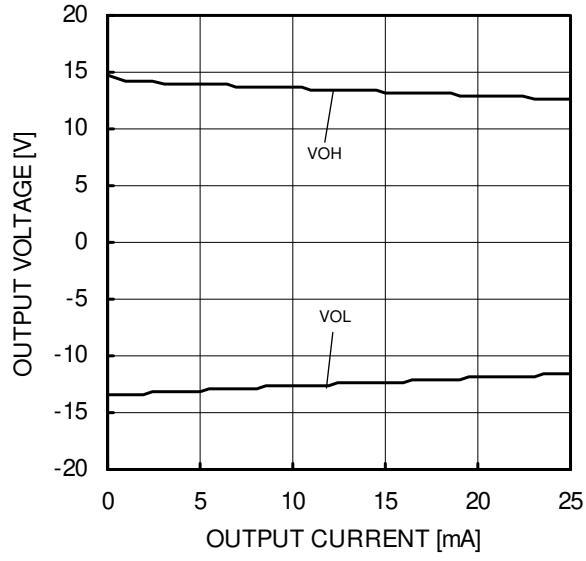


Fig.9
Maximum Output Voltage
- Output Current
(VCC/VEE=+15V/-15V, Ta=25°C)

(*) The above data is measurement value of typical sample, it is not guaranteed.

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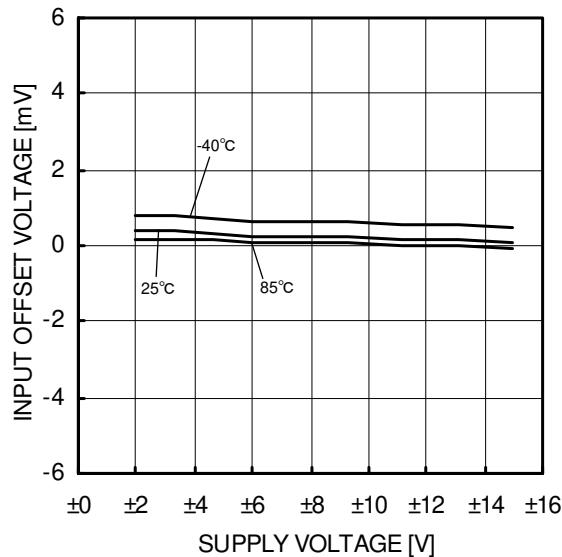


Fig.10
Input Offset Voltage - Supply Voltage
($V_{icm}=0V$, $V_{out}=0V$)

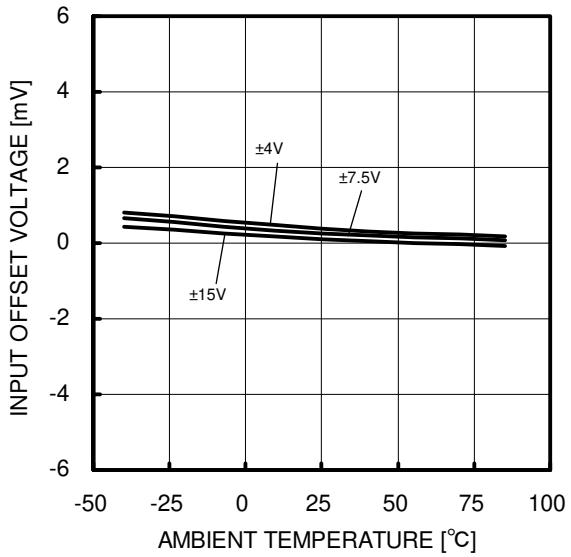


Fig.11
Input Offset Voltage - Ambient Temperature
($V_{icm}=0V$, $V_{out}=0V$)

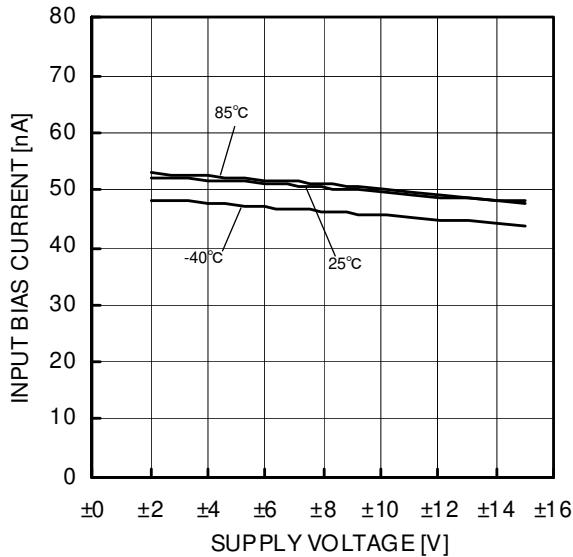


Fig.12
Input Bias Current - Supply Voltage
($V_{icm}=0V$, $V_{out}=0V$)

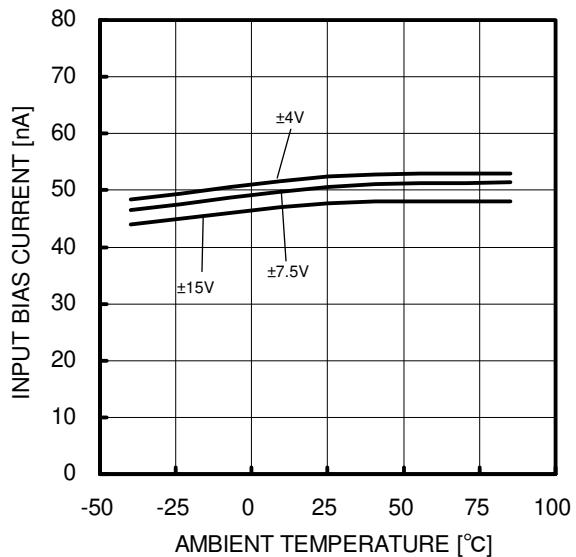


Fig.13
Input Bias Current - Ambient Temperature
($V_{icm}=0V$, $V_{out}=0V$)

(*) The above data is measurement value of typical sample, it is not guaranteed.

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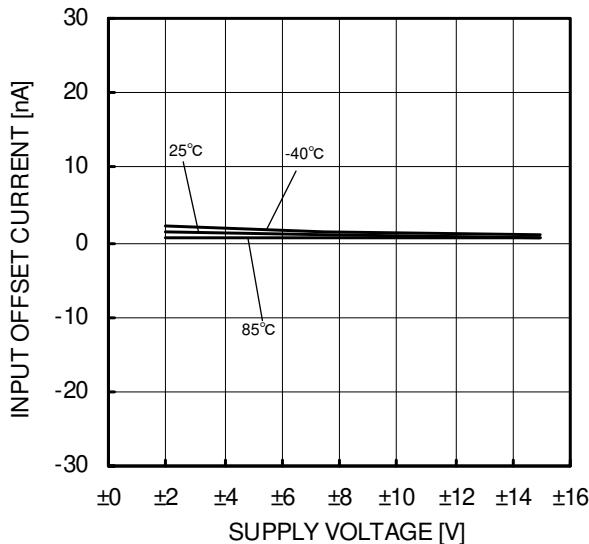


Fig.14
Input Offset Current - Supply Voltage
($V_{ICM}=0V$, $V_{out}=0V$)

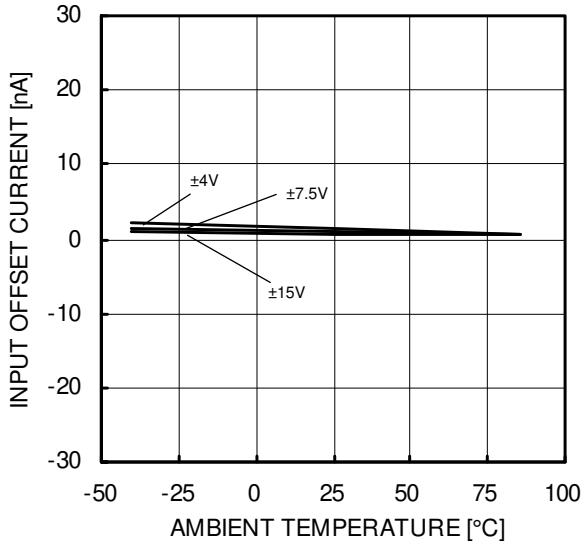


Fig.15
Input Offset Current -
Ambient Temperature
($V_{ICM}=0V$, $V_{out}=0V$)

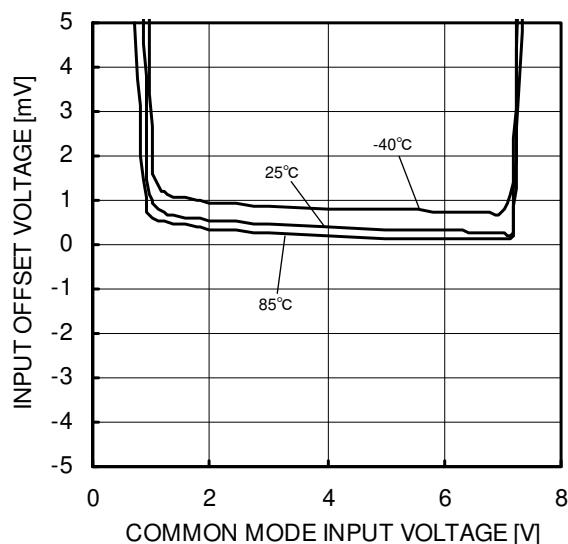


Fig.16
Input Offset Voltage
- Common Mode Input Voltage
($V_{CC}=8V$, $V_{out}=4V$)

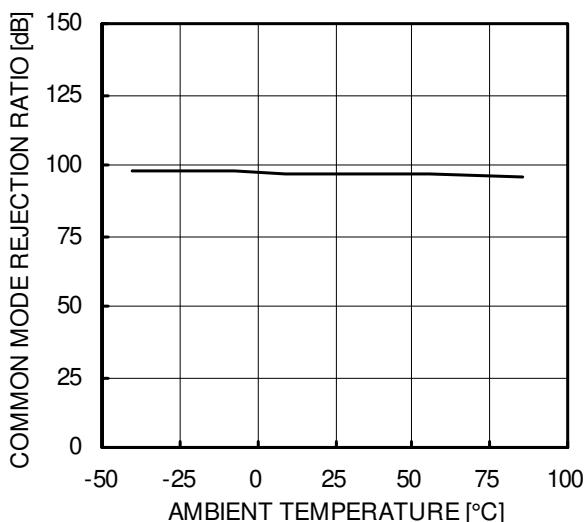


Fig.17
Common Mode Rejection Ratio
- Ambient Temperature
($V_{CC}/V_{EE}=+15V/-15V$, $V_{ICM}=-12V$ to $+12V$)

(*) The above data is measurement value of typical sample, it is not guaranteed.

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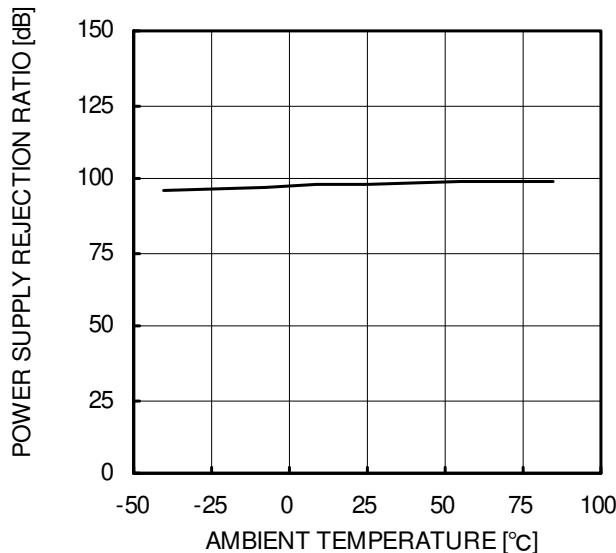


Fig.18
Power Supply Rejection Ratio
- Ambient Temperature
(VCC/VEE=+4V/-4V to +15V/-15V)

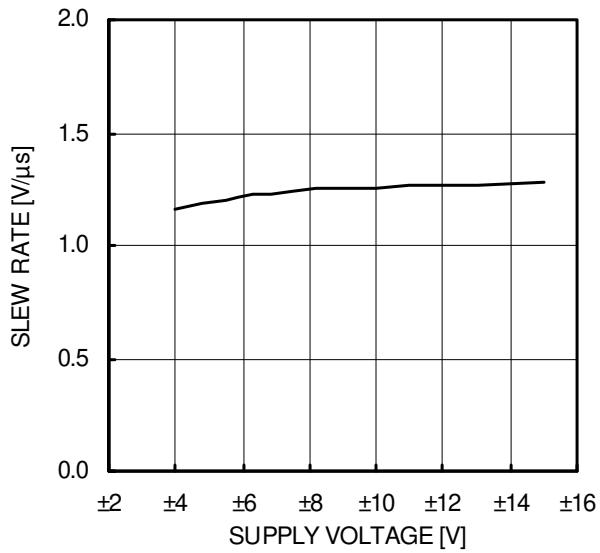


Fig.19
Slew Rate - Supply Voltage
(CL=100pF, RL=2kΩ, Ta=25°C)

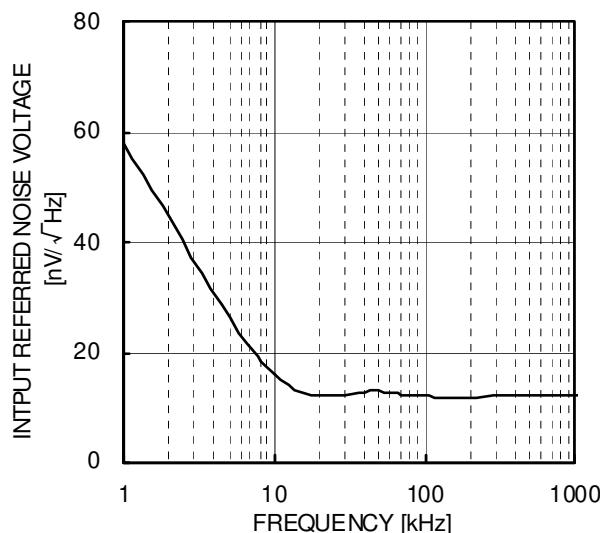


Fig.20
Equivalent Input Noise Voltage - Frequency
(VCC/VEE=+15V/-15V, RS=100Ω, Ta=25°C)

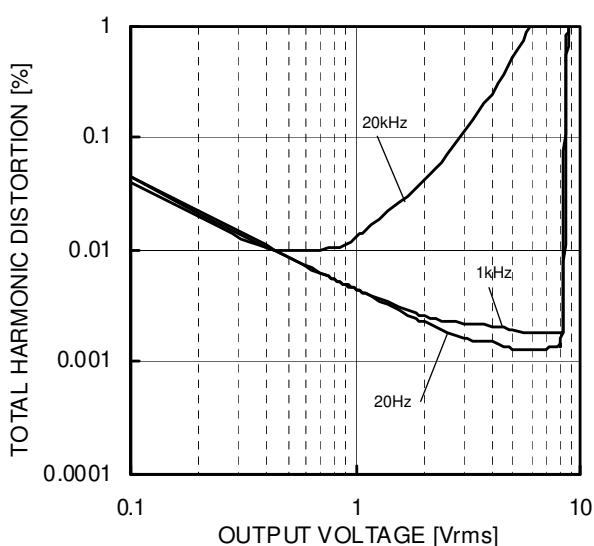


Fig.21
Total Harmonic Distortion -Output Voltage
RL=2kΩ, 80kHz-LPF, Ta=25°C

(*) The above data is measurement value of typical sample, it is not guaranteed.

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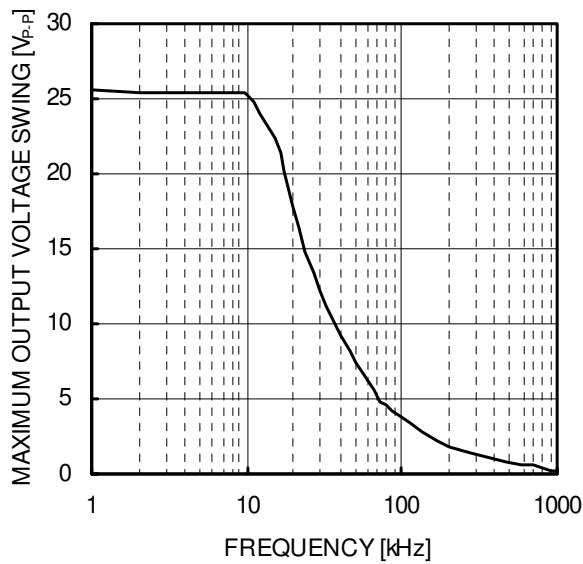


Fig.22
Maximum Output Voltage Swing - Frequency
(VCC/VEE=+15V/-15V, RL=2kΩ, Ta=25°C)

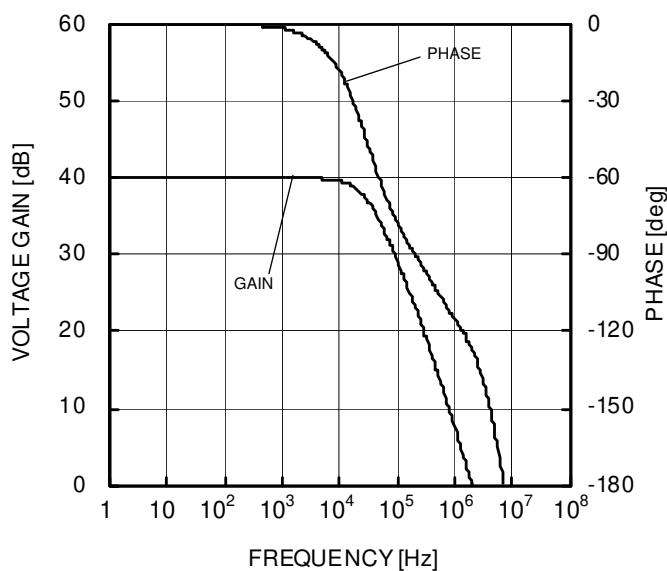


Fig.23
Voltage Gain - Frequency
(VCC/VEE=+15V/-15V, AV=40dB, RL=2kΩ, Ta=25°C)

(*) The above data is measurement value of typical sample, it is not guaranteed.

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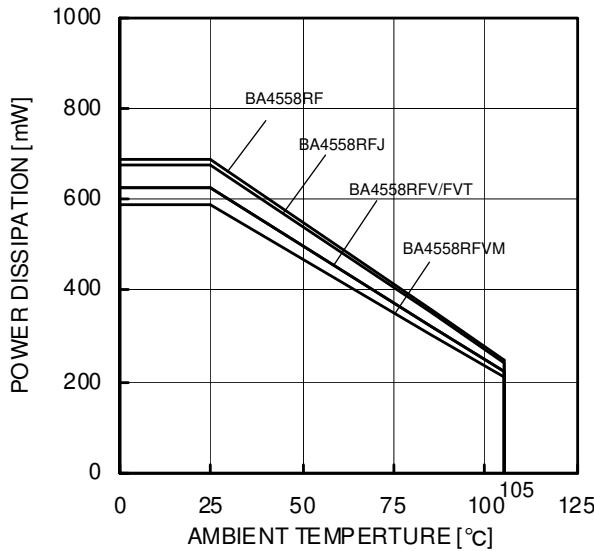


Fig.24
Derating Curve

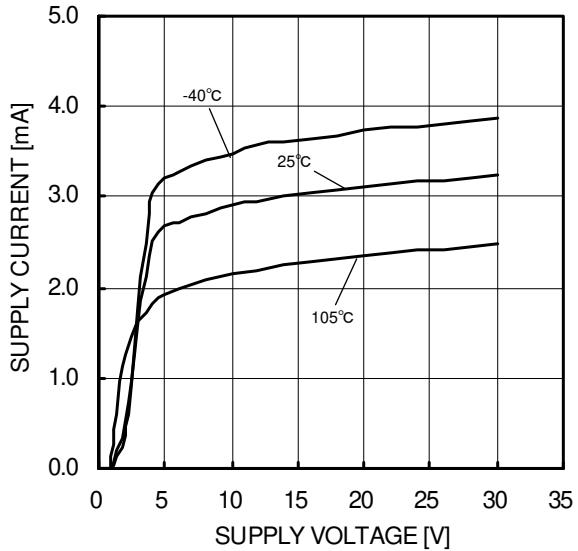


Fig.25
Supply Current - Supply Voltage

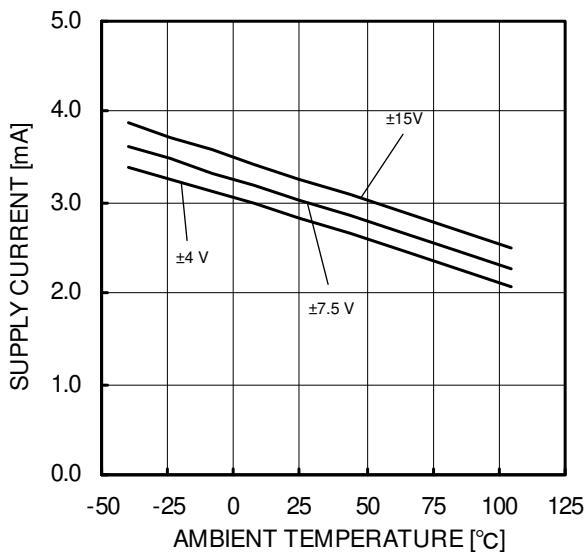


Fig.26
Supply Current - Ambient Temperature

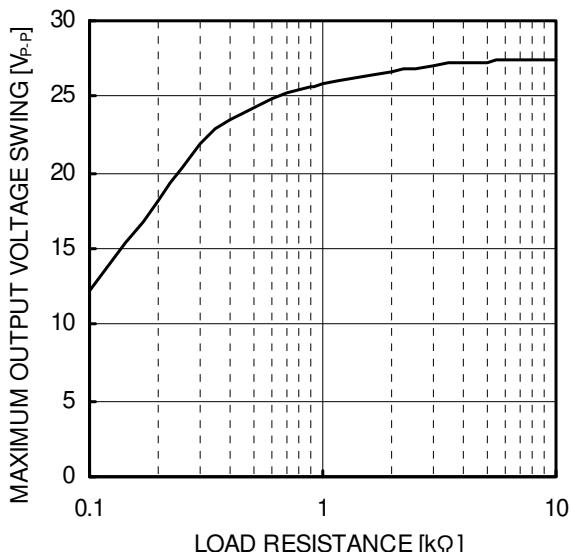


Fig.27
Maximum Output Voltage Swing
- Load Resistance
(VCC/VEE=+15V/-15V, Ta=25°C)

(*) The above data is measurement value of typical sample, it is not guaranteed.

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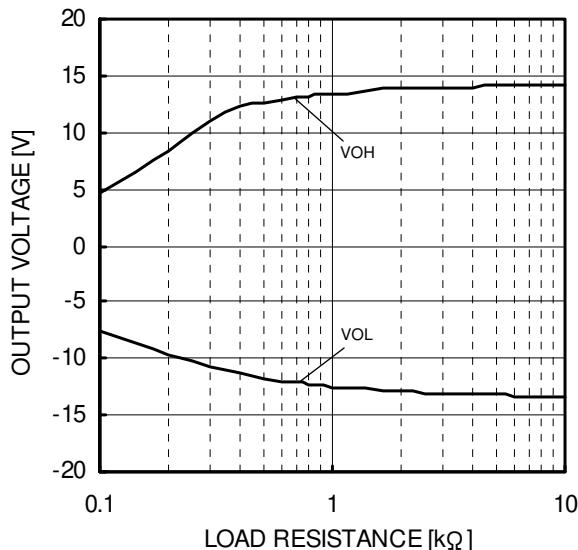


Fig.28
Maximum Output Voltage
- Load Resistance
(VCC/VEE=+15V/-15V, Ta=25°C)

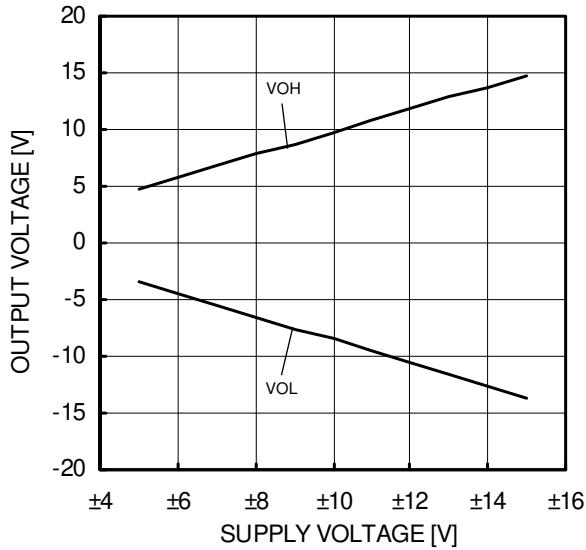


Fig.29
Maximum Output Voltage
- Supply Voltage
(RL=2kΩ, Ta=25°C)

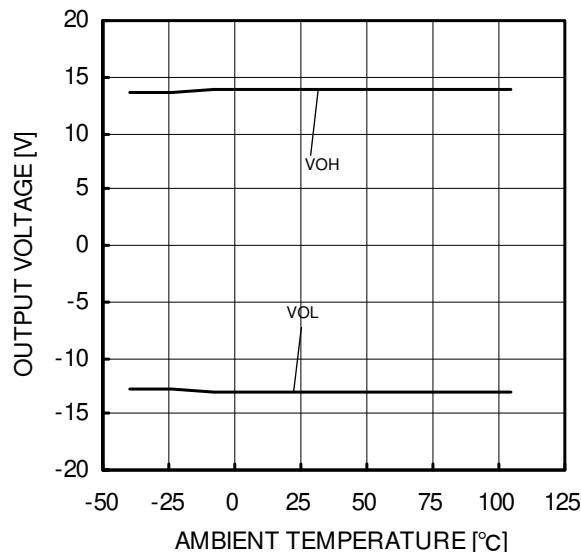


Fig.30
Maximum Output Voltage
- Ambient Temperature
(VCC/VEE=+15V/-15V, RL=2kΩ)

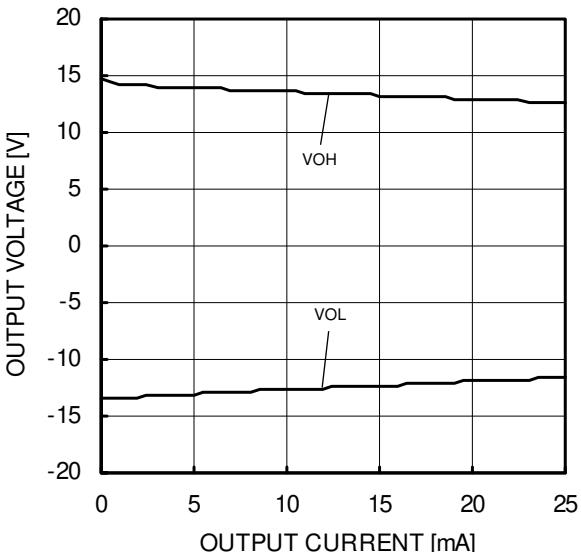


Fig.31
Maximum Output Voltage
- Output Current
(VCC/VEE=+15V/-15V, Ta=25°C)

(*) The above data is measurement value of typical sample, it is not guaranteed.

○ BA4558R

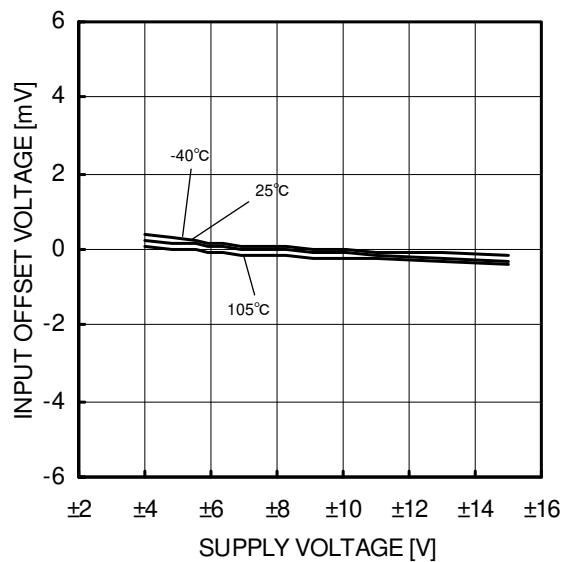


Fig.32
Input Offset Voltage - Supply Voltage
($V_{icm}=0V$, $V_{out}=0V$)

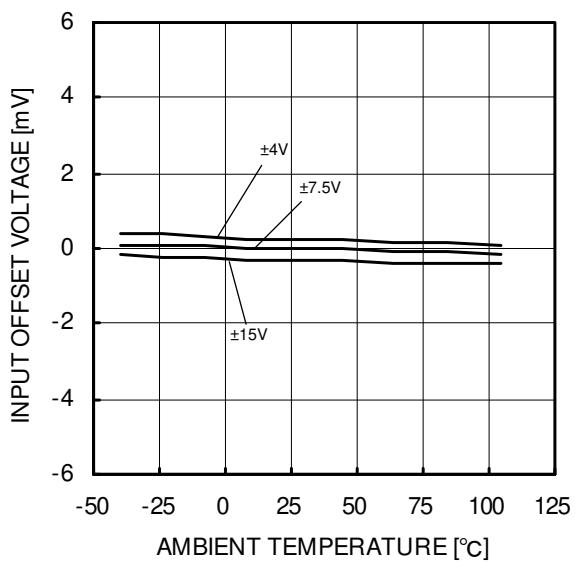


Fig.33
Input Offset Voltage - Ambient Temperature
($V_{icm}=0V$, $V_{out}=0V$)

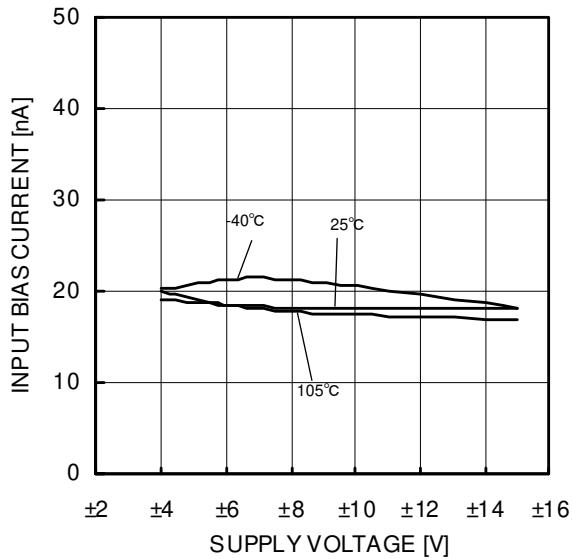


Fig.34
Input Bias Current - Supply Voltage
($V_{icm}=0V$, $V_{out}=0V$)

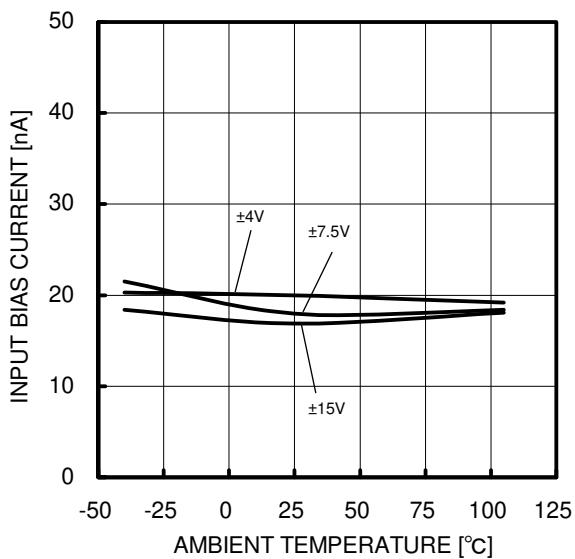


Fig.35
Input Bias Current - Ambient Temperature
($V_{icm}=0V$, $V_{out}=0V$)

(*) The above data is measurement value of typical sample, it is not guaranteed.

○ BA4558R

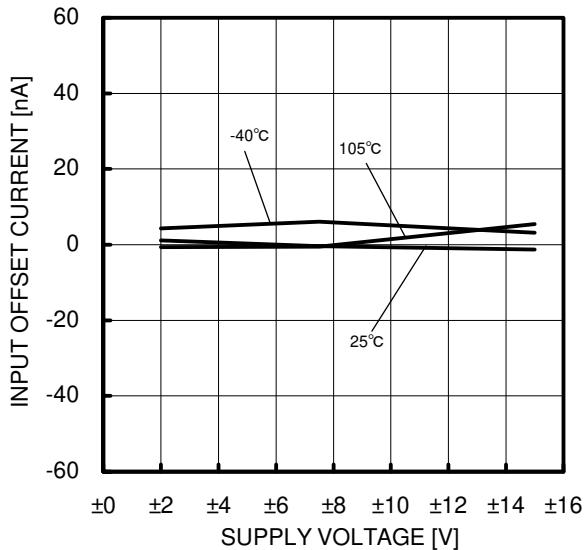


Fig.36
Input Offset Current - Supply Voltage
($V_{icm}=0V$, $V_{out}=0V$)

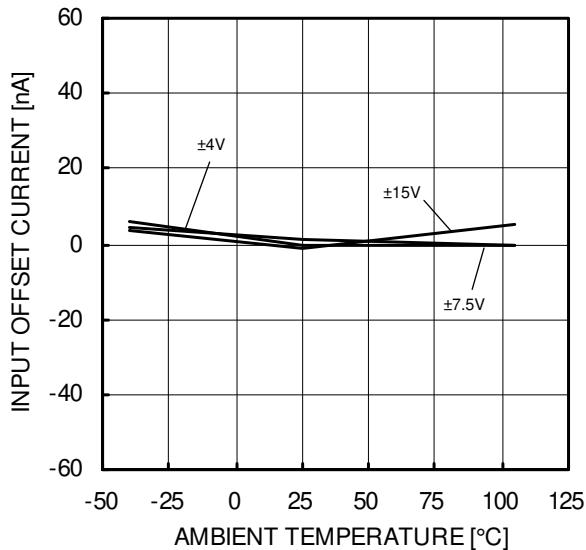


Fig.37
Input Offset Current - Ambient Temperature
($V_{icm}=0V$, $V_{out}=0V$)

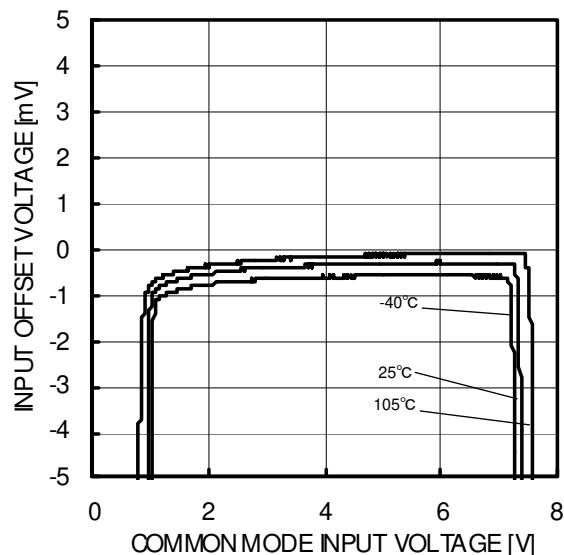


Fig.38
Input Offset Voltage
- Common Mode Input Voltage
($V_{CC}=8V$, $V_{out}=4V$)

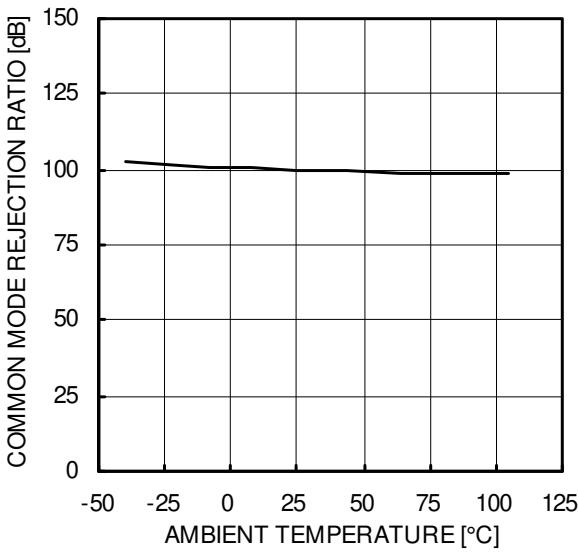


Fig.39
Common Mode Rejection Ratio
- Ambient Temperature
($V_{CC}/V_{EE}=+15V/-15V$, $V_{icm}=-12V$ to $+12V$)

(*) The above data is measurement value of typical sample, it is not guaranteed.

○ BA4558R

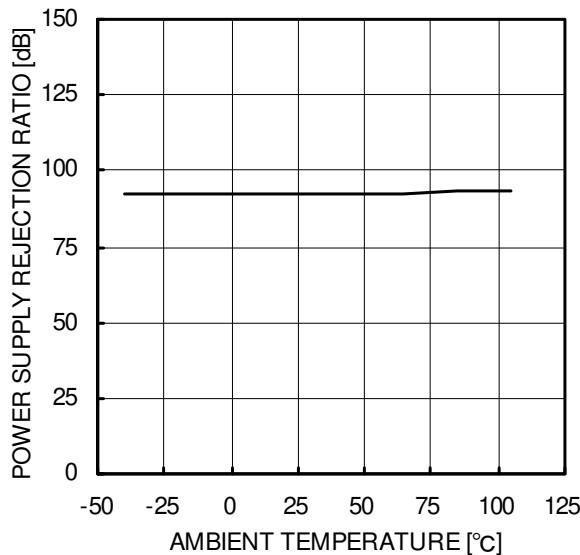


Fig.40
Power Supply Rejection Ratio
- Ambient Temperature
(VCC/VEE=+4V/-4V to +15V/-15V)

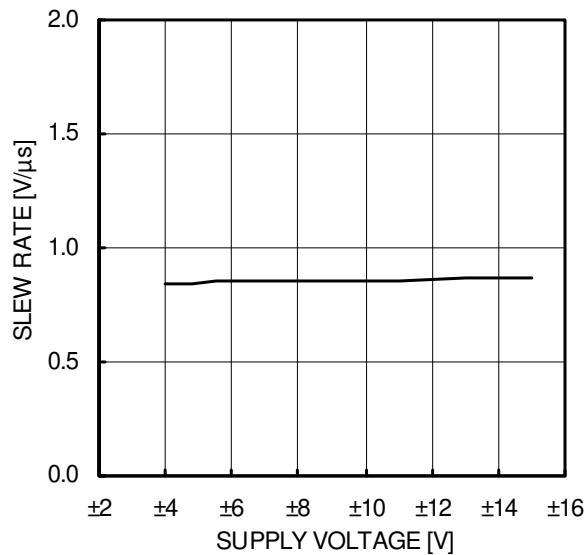


Fig.41
Slew Rate - Supply Voltage
(CL=100pF, RL=2kΩ, Ta=25°C)

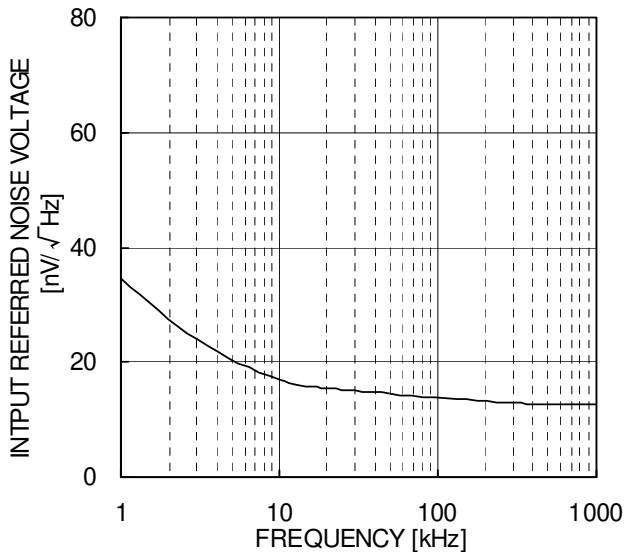


Fig.42
Equivalent Input Noise Voltage - Frequency
VCC/VEE=+15V/-15V, RS=100Ω, Ta=25°C

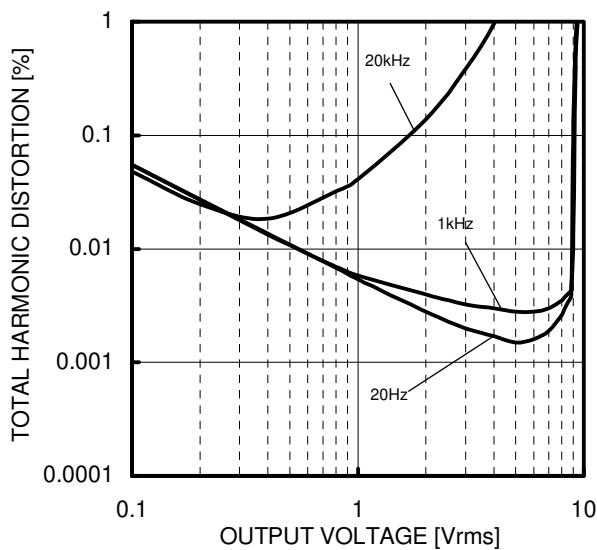


Fig.43
Total Harmonic Distortion - Output Voltage
(VCC/VEE=+15V/-15V, AV=20dB,
RL=2kΩ, 80kHz-LPF, Ta=25°C)

(*) The above data is measurement value of typical sample, it is not guaranteed.

○ BA4558R

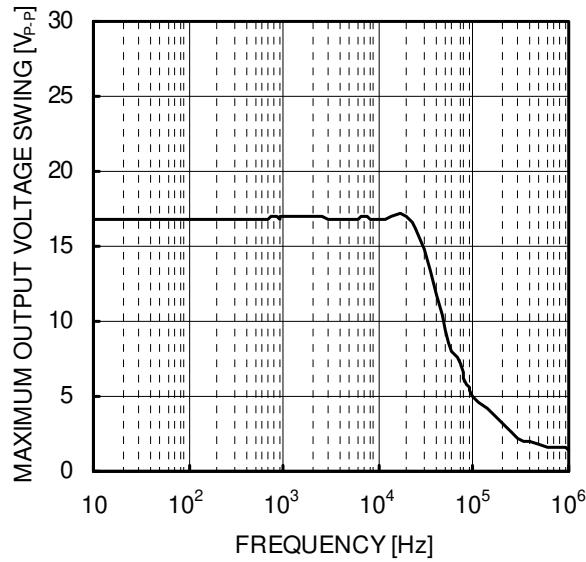


Fig.44
Maximum Output Voltage Swing – Frequency
(VCC/VEE=+15V/-15V, RL=2kΩ, Ta=25°C)

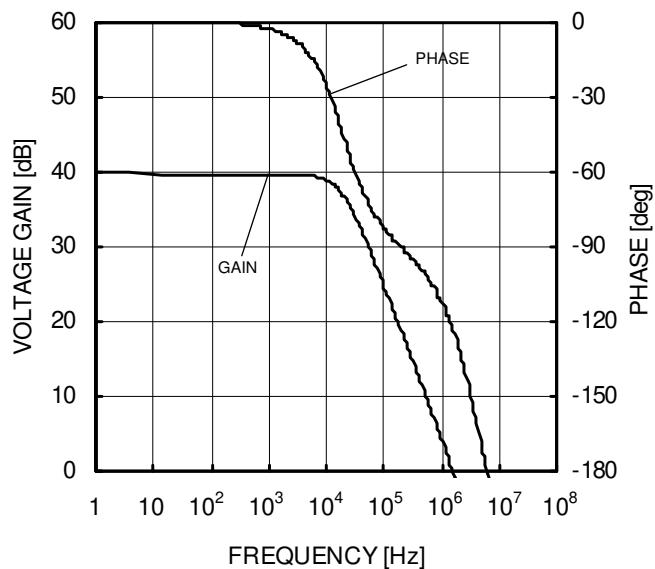


Fig.45
Voltage Gain - Frequency
(VCC/VEE=+15V/-15V, AV=40dB, RL=2kΩ, Ta=25°C)

(*) The above data is measurement value of typical sample, it is not guaranteed.

● Application Information
Test circuit1 NULL method

VCC, VEE, EK, Vicm Unit: V

Parameter	VF	S1	S2	S3	VCC	VEE	EK	Vicm	calculation
Input Offset Voltage	VF1	ON	ON	OFF	15	-15	0	0	1
Input Offset Current	VF2	OFF	OFF	OFF	15	-15	0	0	2
Input Bias Current	VF3	OFF	ON	OFF	15	-15	0	0	3
	VF4	ON	OFF						
Large Signal Voltage Gain	VF5	ON	ON	ON	15	-15	0	0	4
	VF6				15	-15	0	0	
Common-mode Rejection Ratio (Input common-mode Voltage Range)	VF7	ON	ON	OFF	3	-27	0	0	5
	VF8				27	-3	0	0	
Power Supply Rejection Ratio	VF9	ON	ON	OFF	4	-4	0	0	6
	VF10				15	-15	0	0	

-Calculation-

1. Input Offset Voltage (Vio)

$$V_{IO} = \frac{|VF1|}{1 + R_f / R_s} [V]$$

2. Input Offset Current (lio)

$$I_{IO} = \frac{|VF2 - VF1|}{R_i \times (1 + R_f / R_s)} [A]$$

3. Input Bias Current (lb)

$$I_b = \frac{|VF4 - VF3|}{2 \times R_i \times (1 + R_f / R_s)} [A]$$

4. Large Signal Voltage Gain (Av)

$$A_v = 20 \times \log \frac{\Delta EK \times (1 + R_f / R_s)}{|VF5 - VF6|} [\text{dB}]$$

5. Common-mode Rejection Ration (CMRR)

$$CMRR = 20 \times \log \frac{\Delta Vicm \times (1 + R_f / R_s)}{|VF8 - VF7|} [\text{dB}]$$

6. Power supply rejection ratio (PSRR)

$$PSRR = 20 \times \log \frac{\Delta Vcc \times (1 + R_f / R_s)}{|VF10 - VF9|} [\text{dB}]$$

Test Circuit 2 Switch Condition

SW No.	SW1	SW2	SW3	SW4	SW5	SW6	SW7	SW8	SW9	SW10	SW11	SW12	SW13	SW14
Supply Current	OFF	OFF	OFF	ON	OFF	ON	OFF	OFF	OFF	OFF	OFF	OFF	OFF	OFF
High Level Output Voltage	OFF	OFF	ON	OFF	OFF	ON	OFF	OFF	ON	OFF	OFF	OFF	ON	OFF
Low Level Output Voltage	OFF	OFF	ON	OFF	OFF	ON	OFF	OFF	OFF	OFF	OFF	OFF	ON	OFF
Slew Rate	OFF	OFF	OFF	ON	OFF	OFF	OFF	ON	ON	ON	OFF	OFF	OFF	OFF
Gain Bandwidth Product	OFF	ON	OFF	OFF	ON	ON	OFF	OFF	ON	ON	OFF	OFF	OFF	OFF
Equivalent Input Noise Voltage	ON	OFF	OFF	OFF	ON	ON	OFF	OFF	OFF	OFF	ON	OFF	OFF	OFF

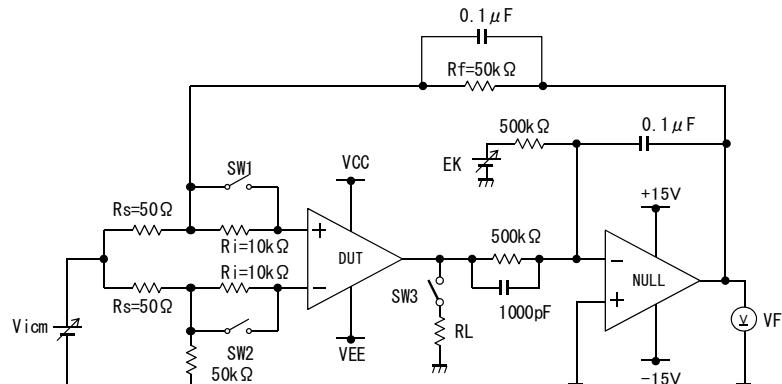


Fig. 46 Test circuit1 (one channel only)

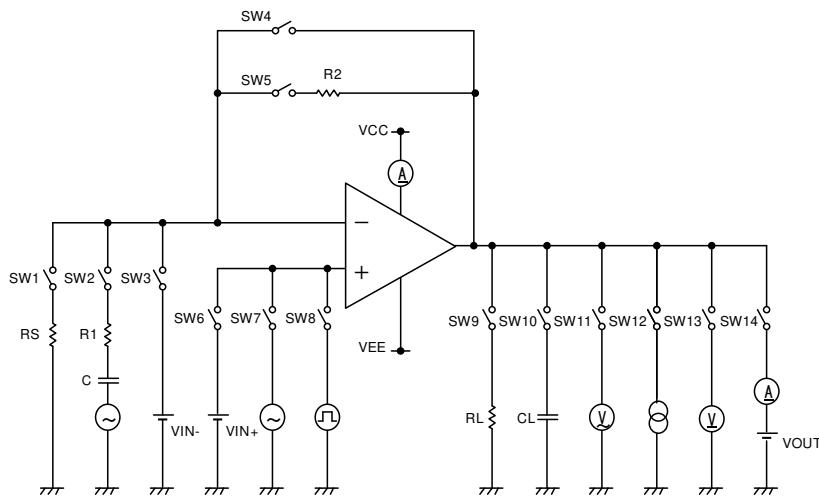


Fig.47 Test Circuit 2 (each Op-Amp)

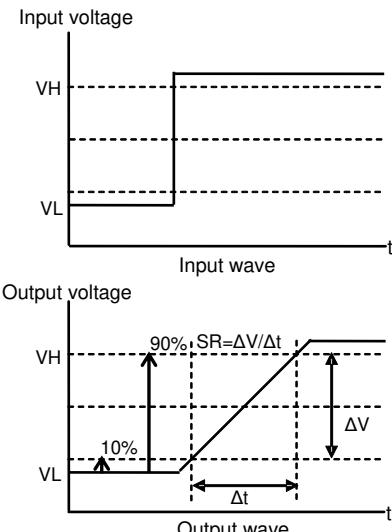


Fig. 48 Slew Rate Input Waveform

Test Circuit 3 Channel Separation

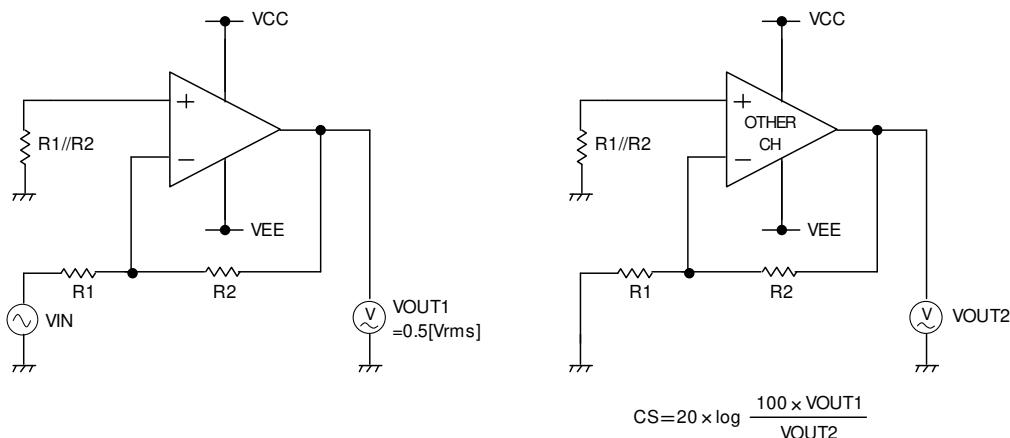


Fig. 49 Test circuit 3
(VCC=+15V, VEE=-15V, R1=1kΩ, R2=100kΩ)

● Power Dissipation

Power dissipation(total loss) indicates the power that can be consumed by IC at $T_a=25^{\circ}\text{C}$ (normal temperature). IC is heated when it consumed power, and the temperature of IC chip becomes higher than ambient temperature. The temperature that can be accepted by IC chip depends on circuit configuration, manufacturing process, and consumable power is limited. Power dissipation is determined by the temperature allowed in IC chip(maximum junction temperature) and thermal resistance of package(heat dissipation capability). The maximum junction temperature is typically equal to the maximum value in the storage temperature range. Heat generated by consumed power of IC radiates from the mold resin or lead frame of the package. The parameter which indicates this heat dissipation capability(hardness of heat release)is called thermal resistance, represented by the symbol $\theta_{ja}^{\circ}\text{C}/\text{W}$.The temperature of IC inside the package can be estimated by this thermal resistance. Fig.50(a) shows the model of thermal resistance of the package. Thermal resistance θ_{ja} , ambient temperature T_a , junction temperature T_j , and power dissipation P_d can be calculated by the equation below:

$$\theta_{ja} = (T_{jmax}-T_a) / P_d \quad ^{\circ}\text{C}/\text{W} \quad \dots \dots \quad (I)$$

Derating curve in Fig.50 (b) indicates power that can be consumed by IC with reference to ambient temperature. Power that can be consumed by IC with reference to ambient temperature. Power that can be consumed by IC begins to attenuate at certain ambient temperature. This gradient is determined by thermal resistance θ_{ja} . Thermal resistance θ_{ja} depends on chip size, power consumption, package, ambient temperature, package condition, wind velocity, etc even when the same of package is used. Thermal reduction curve indicates a reference value measured at a specified condition. Fig.51(c),(d) show a derating curve for an example of BA4558, BA4558R.

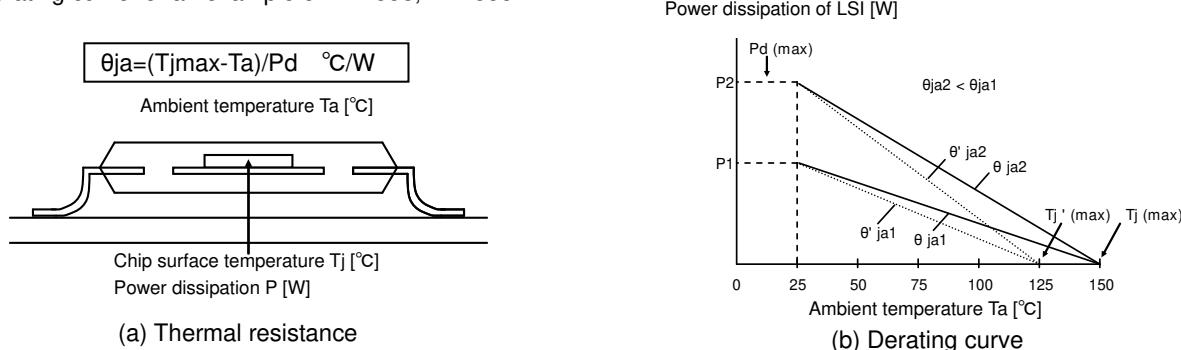
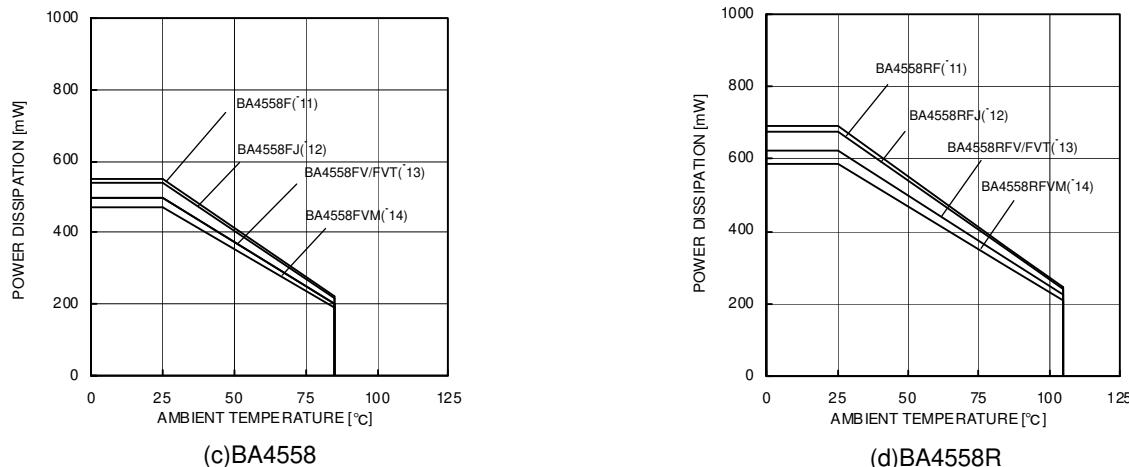


Fig. 50 Thermal resistance and derating curve



(*11)	(*12)	(*13)	(*14)	Unit
5.52	5.4	5	4.7	mW/°C

When using the unit above $T_a=25^{\circ}\text{C}$, subtract the value above per degree $^{\circ}\text{C}$. Permissible dissipation is the value. Permissible dissipation is the value when FR4 glass epoxy board 70mm ×70mm ×1.6mm (cooper foil area below 3%) is mounted.

Fig. 51 Derating curve

Examples of circuit

○Voltage follower

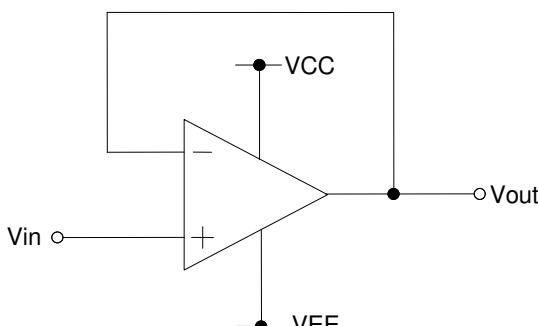


Fig. 52 Voltage follower circuit

Voltage gain is 0 dB.

This circuit controls output voltage (V_{out}) equal input voltage (V_{in}), and keeps V_{out} with stable because of high input impedance and low output impedance.

V_{out} is shown next formula.

$$V_{out} = V_{in}$$

○Inverting amplifier

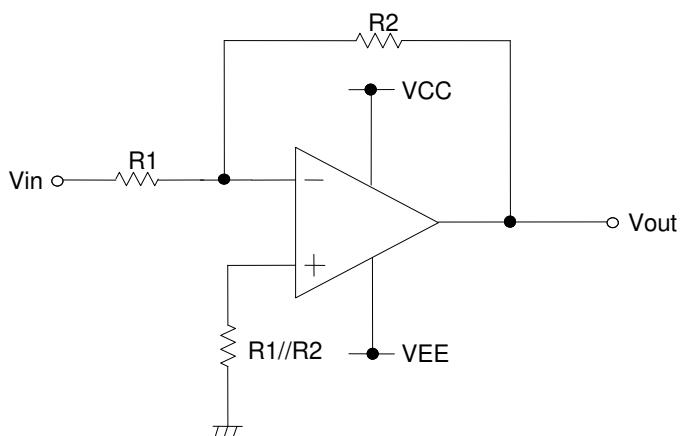


Fig. 53 Inverting amplifier circuit

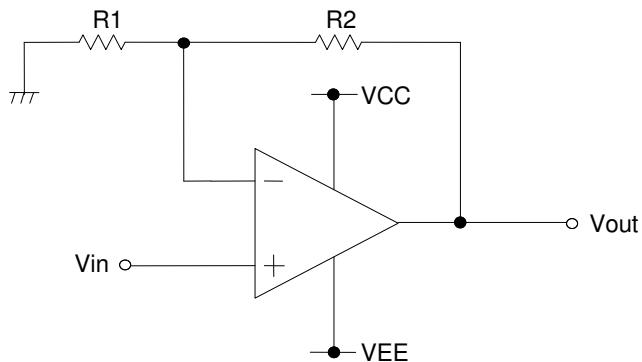
For inverting amplifier, $V_{in}(b)$ Derating curve voltage gain decided R_1 and R_2 , and phase reversed voltage is outputted.

V_{out} is shown next formula.

$$V_{out} = -(R_2/R_1) \cdot V_{in}$$

Input impedance is R_1 .

○Non-inverting amplifier



For non-inverting amplifier, V_{in} is amplified by voltage gain decided R_1 and R_2 , and phase is same with V_{in} . V_{out} is shown next formula.

$$V_{out} = (1 + R_2/R_1) \cdot V_{in}$$

This circuit realizes high input impedance because Input impedance is operational amplifier's input Impedance.

Fig. 54 Non-inverting amplifier circuit

●Operational Notes

1) Processing of unused circuit

It is recommended to apply connection (see the Fig.55) and set the non inverting input terminal at the potential within input common-mode voltage range (V_{ICM}), for any unused circuit.

2) Input voltage

Applying $(VEE - 0.3)$ to $(VEE + 36)V$

(BA4558R) to the input terminal is possible without causing deterioration of the electrical characteristics or destruction, irrespective of the supply voltage. However, this does not ensure normal circuit operation. Please note that the circuit operates normally only when the input voltage is within the common mode input voltage range of the electric characteristics.

3) Maximum output voltage

Because the output voltage range becomes narrow as the output current increases, design the application with margin by considering changes in electrical characteristics and temperature characteristics.

4) Short-circuit of output terminal

When output terminal and VCC or VEE terminal are shorted, excessive Output current may flow under some conditions, and heating may destroy IC. It is necessary to connect a resistor as shown in Fig.56, thereby protecting against load shorting.

5) Power supply (split supply / single supply) in used

Op-amp operates when specified voltage is applied between VCC and VEE. Therefore, the single supply Op-Amp can be used for double supply Op-Amp as well.

6) Power dissipation (P_d)

Use a thermal design that allows for a sufficient margin in light of the power dissipation (P_d) in actual operating conditions.

7) Short-circuit between pins and wrong mounting

Pay attention to the assembly direction of the ICs. Wrong mounting direction or shorts between terminals, GND, or other components on the circuits, can damage the IC.

8) Use in strong electromagnetic field

Using the ICs in strong electromagnetic field can cause operation malfunction.

9) Radiation

This IC is not designed to be radiation-resistant.

10) IC Handling

When stress is applied to IC because of deflection or bend of board, the characteristics may fluctuate due to piezoelectric (piezo) effect.

11) Inspection on set board

During testing, turn on or off the power before mounting or dismounting the board from the test Jig. Do not power up the board without waiting for the output capacitors to discharge. The capacitors in the low output impedance terminal can stress the device. Pay attention to the electro static voltages during IC handling, transportation, and storage.

12) Output capacitor

When VCC terminal is shorted to VEE (GND) potential and an electric charge has accumulated on the external capacitor, connected to output terminal, accumulated charge may be discharged VCC terminal via the parasitic element within the circuit or terminal protection element. The element in the circuit may be damaged (thermal destruction). When using this IC for an application circuit where there is oscillation, output capacitor load does not occur, as when using this IC as a voltage comparator. Set the capacitor connected to output terminal below $0.1\mu F$ in order to prevent damage to IC.

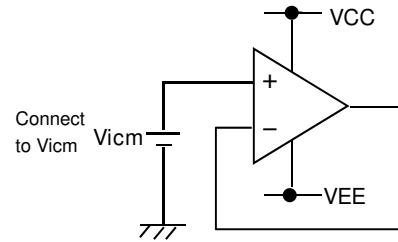


Fig. 55 The example of application circuit for unused op-amp

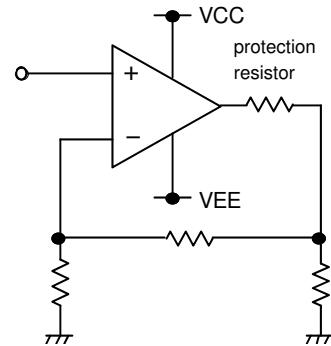


Fig. 56 The example of output short protection

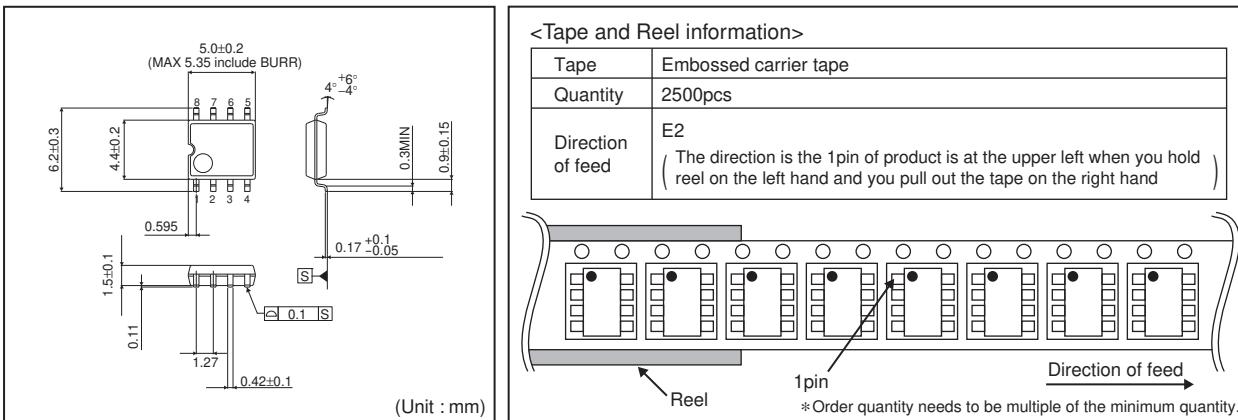
Status of this document

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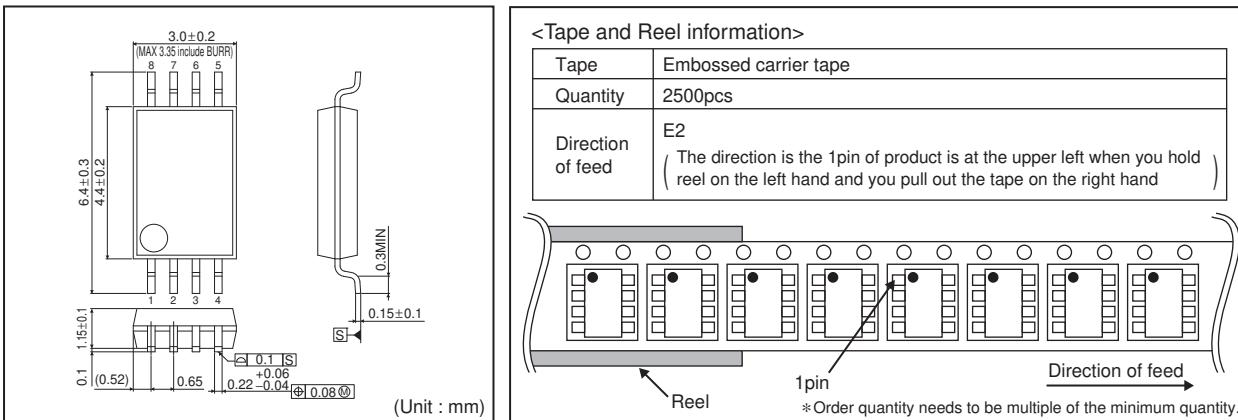
If there are any differences in translation version of this document formal version takes priority.

●Physical Dimensions Tape and Reel Information

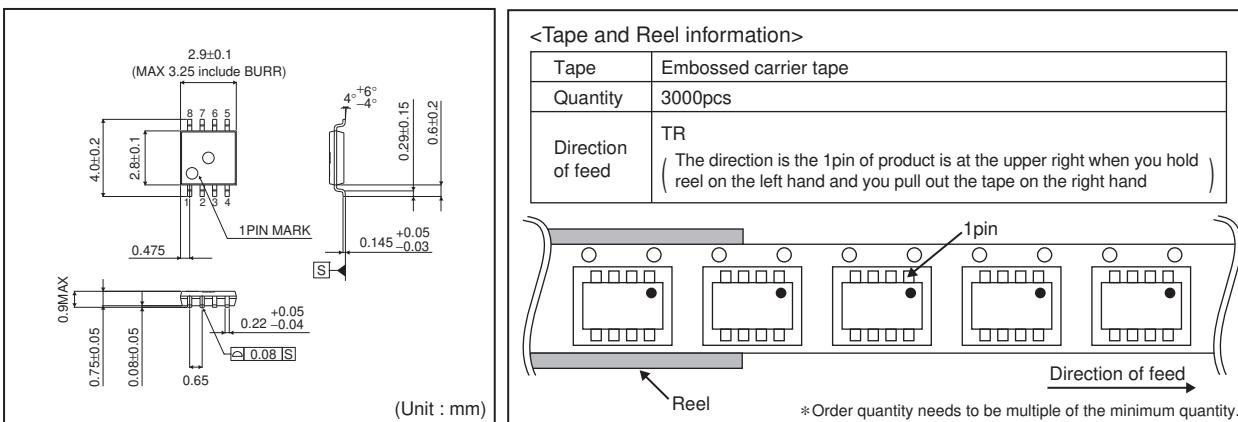
SOP8



SSOP-B8



MSOP8



TSSOP-B8

